NSN 5961-01-118-3913

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-118-3913 **Inclosure Material:** Metal **Overall Length:** 0.272 inches **Terminal Length:** 1.050 inches **Overall Diameter:** 0.630 inches **End Application:** Envir system 76301 fscm Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-21 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 70210-615-014 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 1 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: